

32-Tap Digitally Programmable Potentiometer (DPP™)



FEATURES

- 32-position linear taper potentiometer
- Low power CMOS technology
- Single supply operation: 2.5V 6V
- Increment up/down serial interface
- Resistance values: $10k\Omega$, $50k\Omega$ and $100k\Omega$
- Available in PDIP, SOIC, TSSOP, MSOP and space saving 2 x 2.5mm TDFN packages

APPLICATIONS

- Automated product calibration
- Remote control adjustments
- Offset, gain and zero control
- Tamper-proof calibrations
- Contrast, brightness and volume controls
- Motor controls and feedback systems
- Programmable analog functions

For Ordering Information details, see page 13.

DESCRIPTION

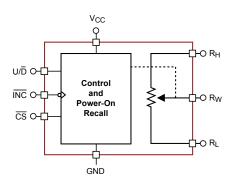
The CAT5115 is a single digitally programmable potentiometer (DPP™) designed as a electronic replacement for mechanical potentiometers and trim pots. Ideal for automated adjustments on high volume production lines, they are also well suited for applications where equipment requiring periodic adjustment is either difficult to access or located in a hazardous or remote environment.

The CAT5115 contains a 32-tap series resistor array connected between two terminals R_H and R_L . An up/down counter and decoder that are controlled by three input pins, determines which tap is connected to the wiper, R_w. The wiper is always set to the mid point, tap 15 at power up. The tap position is not stored in memory. Wiper-control of the CAT5115 is accomplished with three input control pins, \overline{CS} , U/\overline{D} , and INC. The INC input increments the wiper in the direction which is determined by the logic state of the U/D input. The CS input is used to select the device.

The digitally programmable potentiometer can be used as a three-terminal resistive divider or as a two-terminal variable resistor. DPPs bring variability and programmability to a wide variety of applications including control, parameter adjustments, and signal processing.

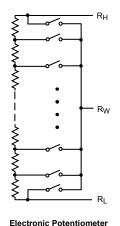
For a pin-compatible device that recalls a stored tap position on power-up refer to the CAT5114 data sheet.

FUNCTIONAL DIAGRAM



General

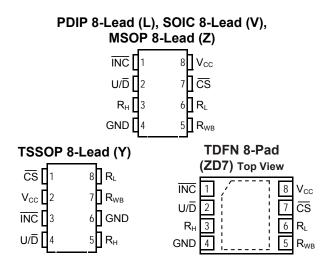
Vnn GND CS DECODER R_W/V_W INC U/D R_L/V_L



Detailed

Implementation

PIN CONFIGURATION



PIN FUNCTION

INC: Increment Control Input

The \overline{INC} input moves the wiper in the up or down direction determined by the condition of the U/ \overline{D} input.

U/D: Up/Down Control Input

The U/ \overline{D} input controls the direction of the wiper movement. When in a high state and \overline{CS} is low, any high-to-low transition on \overline{INC} will cause the wiper to move one increment toward the R_H terminal. When in a low state and \overline{CS} is low, any high-to-low transition on \overline{INC} will cause the wiper to move one increment towards the R_L terminal.

R_H: High End Potentiometer Terminal

 $R_{\rm H}$ is the high end terminal of the potentiometer. It is not required that this terminal be connected to a potential greater than the $R_{\rm L}$ terminal. Voltage applied to the $R_{\rm H}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND.

R_w: Wiper Potentiometer Terminal

 $R_{\rm W}$ is the wiper terminal of the potentiometer. Its position on the resistor array is controlled by the control inputs, $\overline{\rm INC},~{\rm U/\overline{D}}$ and $\overline{\rm CS}.$ Voltage applied to the $R_{\rm W}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND.

R_L: Low End Potentiometer Terminal

 R_{L} is the low end terminal of the potentiometer. It is not required that this terminal be connected to a potential less than the R_{H} terminal. Voltage applied to the R_{L} terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND. R_{L} and R_{H} are electrically interchangeable.

PIN DESCRIPTIONS

Name	Function
ĪNC	Increment Control
U/D	Up/Down Control
R _H	Potentiometer High Terminal
GND	Ground
R_W	Buffered Wiper Terminal
R_L	Potentiometer Low Terminal
C S	Chip Select
V_{CC}	Supply Voltage

CS: Chip Select

The chip select input is used to activate the control input of the CAT5115 and is active low. When in a high state, activity on the $\overline{\text{INC}}$ and $\text{U}/\overline{\text{D}}$ inputs will not affect or change the position of the wiper.

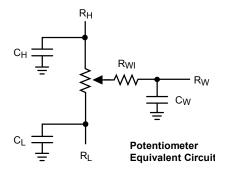
DEVICE OPERATION

The CAT5115 operates like a digitally controlled potentiometer with $R_{\rm H}$ and $R_{\rm L}$ equivalent to the high and low terminals and $R_{\rm W}$ equivalent to the mechanical potentiometer's wiper. There are 32 available tap positions including the resistor end points, $R_{\rm H}$ and $R_{\rm L}$. There are 31 resistor elements connected in series between the $R_{\rm H}$ and $R_{\rm L}$ terminals. The wiper terminal is connected to one of the 32 taps and controlled by three inputs, $\overline{\rm INC}$, U/D and $\overline{\rm CS}$. These inputs control a five-bit up/down counter whose output is decoded to select the wiper position.

With $\overline{\text{CS}}$ set LOW the CAT5115 is selected and will respond to the U/ $\overline{\text{D}}$ and $\overline{\text{INC}}$ inputs. HIGH to LOW transitions on $\overline{\text{INC}}$ will increment or decrement the wiper (depending on the state of the U/ $\overline{\text{D}}$ input and five-bit counter). The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. When the CAT5115 is powered-down, the wiper position is reset. When power is restored, the counter is set to the mid point, tap 15.

OPERATION MODES

ĪNC	cs	U/D	Operation
High to Low	Low	High	Wiper toward H
High to Low	Low	Low	Wiper toward L
High	Low to High	Х	Store Wiper Position
Low	Low to High	Х	No Store, Return to Standby
Х	High	Х	Standby



ABSOLUTE MAXIMUM RATINGS (1)

Parameters	Ratings	Units
Supply Voltage		
V _{CC} to GND	-0.5 to +7V	V
Inputs		
CS to GND	-0.5 to V _{CC} +0.5	V
INC to GND	-0.5 to V _{CC} +0.5	V
U/D to GND	-0.5 to V _{CC} +0.5	V
H to GND	-0.5 to V _{CC} +0.5	V
L to GND	-0.5 to V _{CC} +0.5	V
W to GND	-0.5 to V _{CC} +0.5	V

Parameters	Ratings	Units
Operating Ambient Temperature		
Industrial ('l' suffix)	-40 to +85	°C
Junction Temperature	+150	°C
Storage Temperature	-65 to 150	°C
Lead Soldering (10s max)	+300	°C

RELIABILITY CHARACTERISTICS

Symbol	Parameter	Test Method	Min	Тур	Max	Units
$V_{ZAP}^{(2)}$	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000			V
I _{LTH} ^{(2) (3)}	Latch-Up	JEDEC Standard 17	100			mA
T_DR	Data Retention	MIL-STD-883, Test Method 1008	100			Years
N _{END}	Endurance	MIL-STD-883, Test Method 1003	1,000,000			Stores

DC ELECTRICAL CHARACTERISTICS

Vcc = +2.5V to +6V unless otherwise specified

Power Supply

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{CC}	Operating Voltage Range		2.5	ı	6	V
I _{CC1} Supply Current (Increr	Supply Current (Increment)	$V_{CC} = 6V, f = 1MHz, I_{W} = 0$	_	_	100	μΑ
	Supply Current (Increment)	$V_{CC} = 6V, f = 250kHz, I_W = 0$	_	_	50	μΑ
I _{SB1} ⁽³⁾	Supply Current (Standby)	$\overline{CS} = V_{CC} - 0.3V$ U/ \overline{D} , $\overline{INC} = V_{CC} - 0.3V$ or GND	_	0.01	1	μΑ

- (1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.
- (2) This parameter is tested initially and after a design or process change that affects the parameter.
- (3) Latch-up protection is provided for stresses up to 100mA on address and data pins from -1V to V_{CC} + 1V.
- (4) $I_W =$ source or sink.
- (5) These parameters are periodically sampled and are not 100% tested.

Logic Inputs

Symbol	Parameter	Conditions	Min	Тур	Max	Units
I _{IH}	Input Leakage Current	$V_{IN} = V_{CC}$	_	_	10	μΑ
I _{IL}	Input Leakage Current	V _{IN} = 0V	_	_	-10	μΑ
V _{IH1}	TTL High Level Input Voltage	4 EV / 2 V / 2 E EV /	2	_	V _{CC}	V
V _{IL1}	TTL Low Level Input Voltage	$4.5V \le V_{CC} \le 5.5V$	0	_	0.8	V
V _{IH2}	CMOS High Level Input Voltage	2.51/2.1/ 2.61/	V _{CC} x 0.7	_	V _{CC} + 0.3	V
V_{IL2}	CMOS Low Level Input Voltage	2.5V ≤ V _{CC} ≤ 6V	-0.3	_	V _{CC} x 0.2	V

Potentiometer Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units
		-10 Device		10		
R_{POT}	Potentiometer Resistance	-50 Device		50		kΩ
		-00 Device		100		
	Pot. Resistance Tolerance				±20	%
V_{RH}	Voltage on R _H pin		0		V _{CC}	V
V_{RL}	Voltage on R _L pin		0		V _{CC}	V
	Resolution			3.2		%
INL	Integral Linearity Error	I _W ≤ 2μA		0.5	1	LSB
DNL	Differential Linearity Error	I _W ≤ 2μA		0.25	0.5	LSB
D	Winer Desigtance	V_{CC} = 5V, I_W = 1mA		70	200	Ω
R_{WI}	Wiper Resistance	$V_{CC} = 2.5V, I_W = 1mA$		150	400	Ω
I _W	Wiper Current	(1)			1	mA
TC _{RPOT}	TC of Pot Resistance			±50	±300	ppm/°C
TC _{RATIO}	Ratiometric TC				20	ppm/°C
V _N	Noise	100kHz / 1kHz		8/24		nV/√Hz
C _H /C _L /C _W	Potentiometer Capacitances			8/8/25		pF
fc	Frequency Response	Passive Attenuator, 10kΩ		1.7		MHz

AC CONDITIONS OF TEST

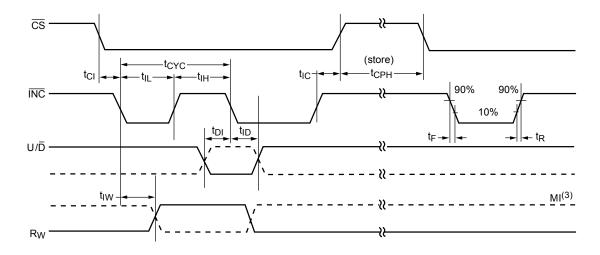
V _{CC} Range	$2.5V \le V_{CC} \le 6.0V$
Input Pulse Levels	$0.2V_{CC}$ to $0.7V_{CC}$
Input Rise and Fall Times	10ns
Input Reference Levels	0.5V _{CC}

AC OPERATING CHARACTERISTICS

 V_{CC} = +2.5V to +6.0V, V_{H} = $V_{\text{CC}},\,V_{\text{L}}$ = 0V, unless otherwise specified

Symbol	Parameter	Min	Typ ⁽¹⁾	Max	Units
t _{CI}	CS to INC Setup	100	_	-	ns
t _{DI}	U/D to INC Setup	50	_	_	ns
t_{ID}	U/D to INC Hold	100	_	_	ns
t_IL	INC LOW Period	250	_	-	ns
t _{IH}	INC HIGH Period	250	_	ı	ns
t _{IC}	INC Inactive to CS Inactive	1	_	_	μs
t_{CPH}	CS Deselect Time	100	_	-	ns
t _{IVV}	INC to V _{OUT} Change	_	1	5	μs
t _{CYC}	INC Cycle Time	1	_	ı	μs
$t_R, t_F^{(2)}$	INC Input Rise and Fall Time	_	_	500	μs
t _{PU} ⁽²⁾	Power-up to Wiper Stable	_	_	1	ms

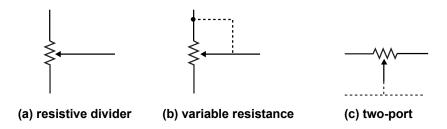
A.C. TIMING



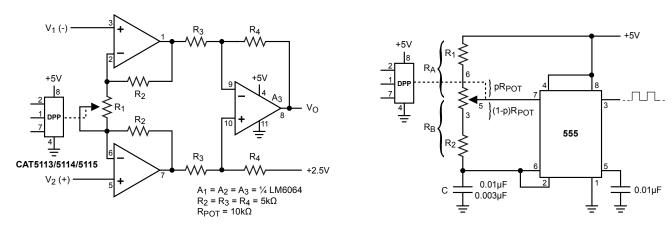
- (1) Typical values are for $T_A = 25$ °C and nominal supply voltage.
- (2) This parameter is periodically sampled and not 100% tested.
- (3) MI in the A.C. Timing diagram refers to the minimum incremental change in the W output due to a change in the wiper position.

APPLICATIONS INFORMATION

POTENTIOMETER CONFIGURATION

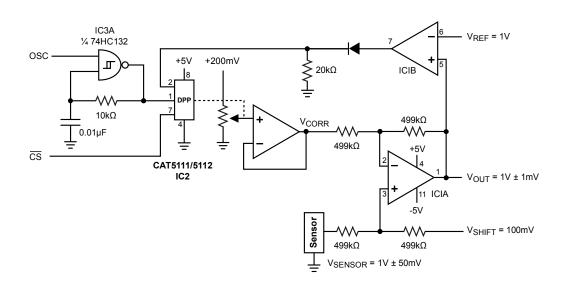


APPLICATIONS

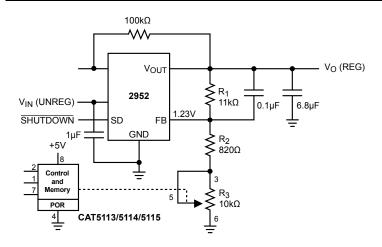


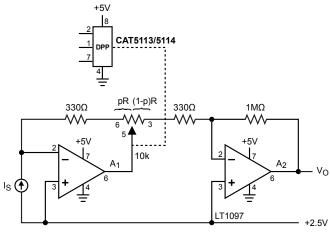
Programmable Instrumentation Amplifier

Programmable Sq. Wave Oscillator (555)



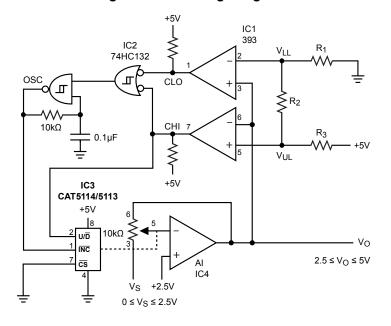
Sensor Auto Referencing Circuit

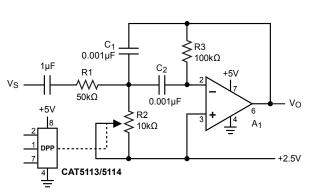




Programmable Voltage Regulator

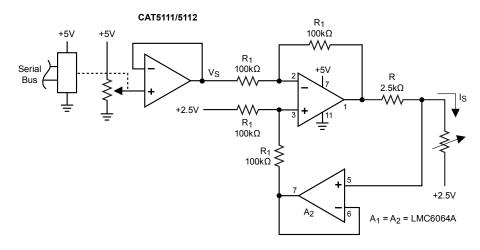
Programmable I to V Converter





Automatic Gain Control

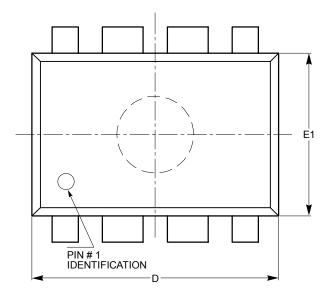
Programmable Bandpass Filter



Programmable Current Source/Sink

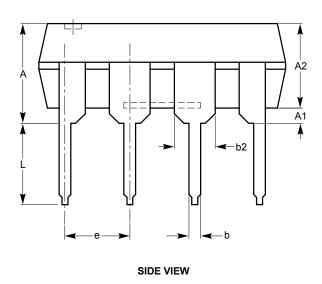
PACKAGE OUTLINE DRAWINGS

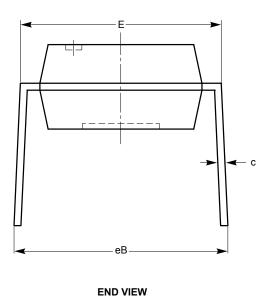
PDIP 8-Lead 300mils (L) (1)(2)



SYMBOL	MIN	NOM	MAX
Α			5.33
A1	0.38		
A2	2.92	3.30	4.95
b	0.36	0.46	0.56
b2	1.14	1.52	1.78
С	0.20	0.25	0.36
D	9.02	9.27	10.16
Е	7.62	7.87	8.25
е		2.54 BSC	
E1	6.10	6.35	7.11
eВ	7.87		10.92
L	2.92	3.30	3.80

TOP VIEW

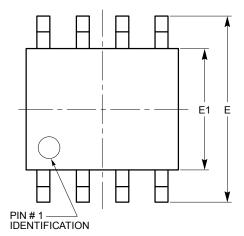




Notes:

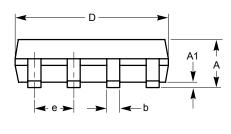
- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC standard MS-001.

SOIC 8-Lead 150mils (V) (1)(2)

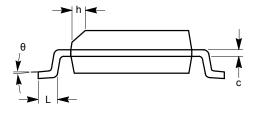


SYMBOL	MIN	NOM	MAX
Α	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
С	0.19		0.25
D	4.80		5.00
Е	5.80		6.20
E1	3.80		4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	0°		8°

TOP VIEW



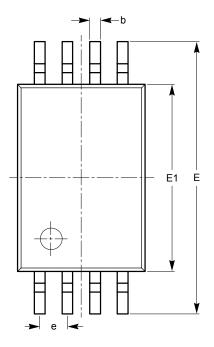
SIDE VIEW



END VIEW

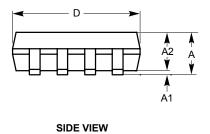
- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MS-012.

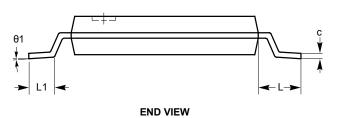
TSSOP 8-Lead 4.4mm (Y) (1)(2)



SYMBOL	MIN	NOM	MAX
Α			1.20
A1	0.05		0.15
A2	0.80	0.90	1.05
b	0.19		0.30
С	0.09		0.20
D	2.90	3.00	3.10
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
е	0.65 BSC		
L	1.00 REF		
L1	0.50	0.60	0.75
θ1	0°		8°

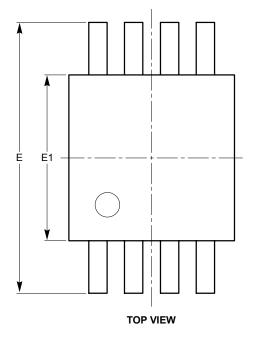
TOP VIEW



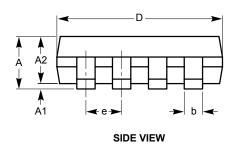


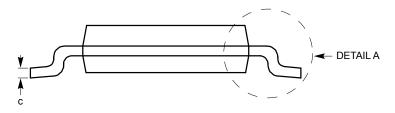
- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MO-153.

MSOP 8-Lead 3.0 x 3.0mm (Z) $^{(1)(2)}$

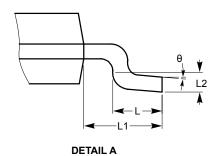


SYMBOL	MIN	NOM	MAX
Α			1.10
A1	0.05	0.10	0.15
A2	0.75	0.85	0.95
b	0.22		0.38
С	0.13		0.23
D	2.90	3.00	3.10
E	4.80	4.90	5.00
E1	2.90	3.00	3.10
е	0.65 BSC		
L	0.40	0.60	0.80
L1	0.95 REF		
L2	0.25 BSC		
θ	0°		6°



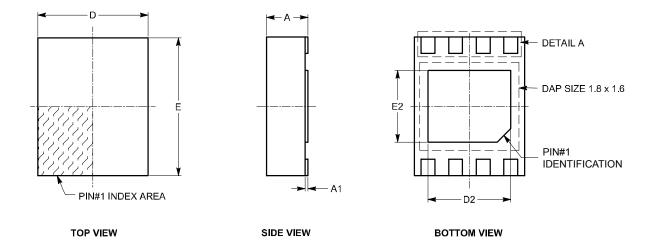


END VIEW

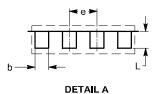


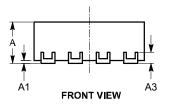
- $\hbox{(1)} \quad \hbox{All dimensions are in millimeters. Angles in degrees.} \\$
- (2) Complies with JEDEC standard MO-187.

TDFN 8-Pad 2 x 2.5mm (ZD7) (1)(2)



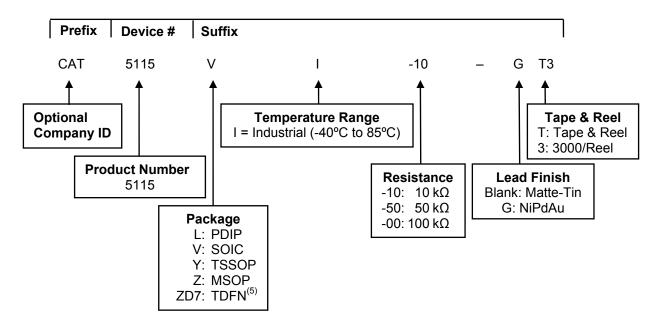
SYMBOL	MIN	NOM	MAX
Α	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3	0.20 REF		
b	0.20	0.25	0.30
D	1.90	2.00	2.10
D2	1.40	1.50	1.60
Е	2.40	2.50	2.60
E2	1.20	1.30	1.40
е	0.50 TYP		
L	0.20	0.30	0.40





- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC standard MO-229.

EXAMPLE OF ORDERING INFORMATION



ORDERING INFORMATION

ORDERABLE PART NUMBER
CAT5115LI-10-G
CAT5115LI-50-G
CAT5115LI-00-G
CAT5115VI-10-GT3
CAT5115VI-50-GT3
CAT5115VI-00-GT3
CAT5115YI-10-GT3
CAT5115YI-50-GT3
CAT5115YI-00-GT3
CAT5115ZI-10-GT3
CAT5115ZI-50-GT3
CAT5115ZI-00-GT3
CAT5115ZD7I-10-T3 ⁽⁶⁾
CAT5115ZD7I-50-T3 ⁽⁶⁾
CAT5115ZD7I-00-T3 ⁽⁶⁾

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free).
- (2) The standard lead finish is NiPdAu.
- (3) This device used in the above example is a CAT5115VI-10-GT3 (SOIC, Industrial Temperature, $10k\Omega$, NiPdAu, Tape & Reel).
- (4) For additional package and temperature options, please contact your nearest ON Semiconductor Sales office.
- (5) TDFN is not available in NiPdAu (-G) version.
- (6) Contact factory for package availability.

REVISION HISTORY

Date	Rev.	Description
25-Sep-03	В	Changed designation to Preliminary. Updated Description. Updated Potentiometer Parameters table.
10-Mar-04	С	Updated Potentiometer Parameters table.
29-Mar-04	D	Changed Green Package marking for SOIC from W to V
12-Apr-04	Е	Updated Tape and Reel specs in Ordering Information
31-Aug-04	F	Deleted I _{CC2} from DC Characteristics table Updated AC Operating Characteristics table Updated A.C. Timing diagram.
06-Jul-07	G	Update Absolute Maximum Ratings table Update DC Electrical Characteristics tables Update AC Conditions of Test table Update all Package Outline Drawings Update Example of Ordering Information Update Ordering Part Number
02-Feb-08	Н	Update Functional Diagram Update Package Outline Drawings
21-Nov-08	I	Change logo and fine print to ON Semiconductor
31-Jul-09	J	Update Ordering Information

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